

PRELIMINARY

Notice: Some parametric limits are subject to change

MITSUBISHI LASER DIODES ML9XX31 SERIES

In GaAsP DFB-LASER DIODE WITH EA MODULATOR

TYPE
NAME

ML9SM31

DESCRIPTION

ML9XX31 series are 10Gbps DFB (Distributed Feedback) laser diodes with a monolithically integrated EA modulator. ML9xx31 is a suitable light source for 10Gbps DWDM transmission, which is applicable to various distances from short reach (SR) to intermediate reach (IR). Available wavelengths are from 1530nm to 1565nm with 0.8nm spacing. ML9SM31 is supplied with the chip-on-carrier type package.

FEATURES

- Available distance : 50km (Max)
- High extinction ratio (Typ. 11dB)
- High - side mode suppression ratio (Typ. 40dB)
- High speed response (Typ. 30psec)

APPLICATION

10Gbps DWDM transmission system

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Conditions | Ratings | Unit |
|--------|-------------------------------|------------|-------------|------|
| IF | Forward current (Laser diode) | CW | 200 | mA |
| VRL | Reverse voltage (Laser diode) | - | 2 | V |
| VEA | Reverse voltage (Modulator) | - | -3 | V |
| Tc | Case temperature | - | +15 to +35 | degC |
| Tstg | Storage temperature | - | -40 to +100 | degC |

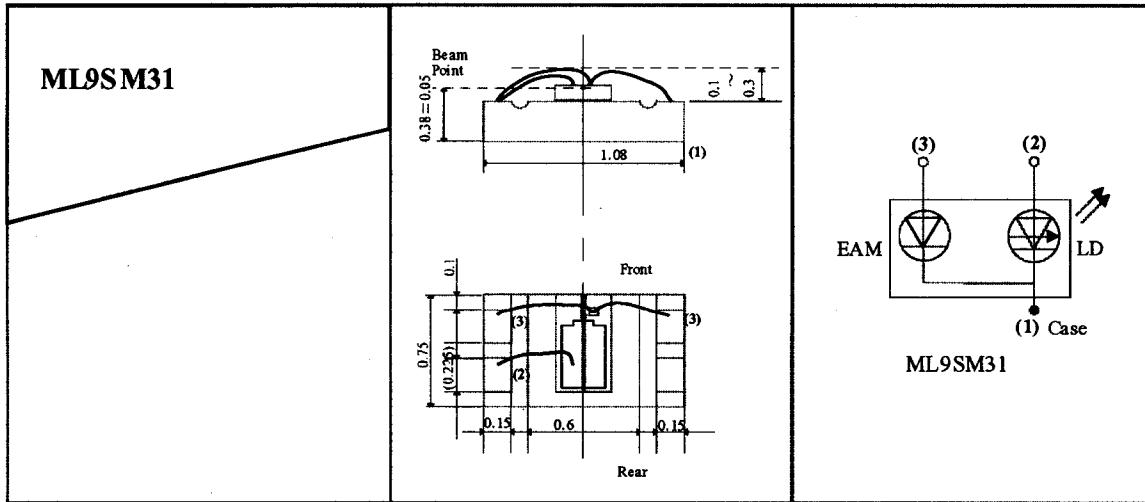
ELECTRICAL/OPTICAL CHARACTERISTICS (Tc=25degC)

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|------------------|---------------------------------------|--|------|-----------|------|------|
| Ith | Threshold current | CW,Vmod=0V | - | 10 | 30 | mA |
| Iop | Operation current | CW,Po=5mW,Vmod=0V | - | 60 | 90 | mA |
| Vop | Operating voltage | CW,Po=5mW,Vmod=0V | - | 1.2 | 1.8 | V |
| λ_p | Peak wavelength | CW,Po=5mW,Vmod=0V | -0.4 | code list | +0.4 | nm |
| $\theta_{//}$ | Beam divergence angle (parallel) | CW,Po=5mW,Vmod=0V | - | 30 | - | deg. |
| θ_{\perp} | Beam divergence angle (perpendicular) | CW,Po=5mW,Vmod=0V | - | 45 | - | deg. |
| Pm | Monitoring output power | CW,Po=5mW,Vmod=0V | - | 1.0 | - | mW |
| f _c | Cut off frequency | CW,Po=5mW ,Vmod=-1V | 10 | 14 | - | GHz |
| tr,tf | Rise and Fall time (10%-90%) | 9.95328Gbps,NRZ,PRBS ²³ -1 | - | 30 | 40 | psec |
| SMSR | Side mode suppression ratio | If >Iop,Vpp=2.5V, Vmod(offset)=0 to -1.0V | 35 | 40 | - | dB |
| Ex | Extinction Ratio | ditto SMF 50km@BER=10 ⁻¹⁰ | 10 | 11 | - | dB |
| Pp | Dispersion Penalty | ditto SMF 50km@BER=10 ⁻¹⁰ | - | - | 2.0 | dB |

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OUTLINE DRAWINGS



Wavelength code list

| Code | Wavelength(nm) | Code | Wavelength(nm) |
|------|----------------|------|----------------|
| 1 | 1529.55 | 24 | 1547.72 |
| 2 | 1530.33 | 25 | 1548.51 |
| 3 | 1531.12 | 26 | 1549.32 |
| 4 | 1531.90 | 27 | 1550.12 |
| 5 | 1532.68 | 28 | 1550.92 |
| 6 | 1533.47 | 29 | 1551.72 |
| 7 | 1534.25 | 30 | 1552.52 |
| 8 | 1535.04 | 31 | 1553.33 |
| 9 | 1535.82 | 32 | 1554.13 |
| 10 | 1536.61 | 33 | 1554.94 |
| 11 | 1537.40 | 34 | 1555.75 |
| 12 | 1538.19 | 35 | 1556.55 |
| 13 | 1538.98 | 36 | 1557.36 |
| 14 | 1539.77 | 37 | 1558.17 |
| 15 | 1540.56 | 38 | 1558.98 |
| 16 | 1541.35 | 39 | 1559.79 |
| 17 | 1542.14 | 40 | 1560.61 |
| 18 | 1542.94 | 41 | 1561.42 |
| 19 | 1543.73 | 42 | 1562.23 |
| 20 | 1544.53 | 43 | 1563.05 |
| 21 | 1545.32 | 44 | 1563.86 |
| 22 | 1546.12 | 45 | 1564.68 |
| 23 | 1546.92 | 46 | 1565.50 |